## NSN 5961-01-368-9015

**Fiig:** A110a0

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-368-9015 **Inclosure Material:** Metal **Overall Length:** 3.620 inches **Overall Height:** 1.460 inches **Overall Width:** 0.200 inches **Mounting Facility Quantity: Component Name And Quantity:** 2 semiconductor device thyristor **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon single semiconductor device thyristor **Voltage Rating In Volts Per Characteristic:** 1000.0 repetitive peak off-state voltage single semiconductor device thyristor **Current Rating Per Characteristic:** 200.00 amperes drain current nanoamperes single semiconductor device thyristor and 90.00 amperes drain current universal single semiconductor device thyristor and 120.00 amperes drain current preset single semiconductor device thyristor **Maximum Operating Tempurature Per Measurement Point:** 85.0 degrees celsius ambient air **Special Features:** Single semiconductor device thyristor junction pattern arrangement: pnpn **Terminal Type And Quantity:** 4 tab, solder lug and 3 screw Shelf Life: N/a **Unit Of Measure: Demilitarization:** No